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## ABSTRACT OF THE DISCLOSURE

A semiconductor light emitting device includes: a silicon substrate; and a plurality of column-shaped multilayered structures formed on the silicon substrate in such a manner that the column-shaped multilayered structures are insulated from one another, the column-shaped multilayered structures being made of a nitride semiconductor material, and each column-shaped multilayered structure including a light emitting layer, wherein the column-shaped multilayered structures are connected to one another by an electrode.